

30V, 395A, 0.48m N-channel Power SGT MOSFET

JMSL030STG

Product Summary

Parameters	Value	Unit
V_{DSS}	30	V
$V_{GS(th_Typ)}$	1.6	V
$I_D(@V_{GS}=10V)$	395	A
$R_{DS(ON_Typ)}(@V_{GS}=10V)$	0.48	m Ω

Ordering Information

Device	Marking	MSL	Form	Package	Reel(pcs)	Per Carton (pcs)
JMSL030STG-13	SL030ST	1	Tape&Reel	PDFN5x6-8L	5000	50000

Absolute Maximum Ratings (@ $T_C = 25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Value	Unit
V_{DS}	Drain-to-Source Voltage	30	V
V_{GS}	Gate-to-Source Voltage	± 20	V
I_D		$T_C = 25^\circ\text{C}$ $T_C = 100^\circ\text{C}$	A
I_{DM}	Pulsed Drain Current ⁽¹⁾	Refer to Fig.4	A
E_{AS}	Single Pulsed Avalanche Energy ⁽²⁾	1118	mJ
P_D		$T_C = 25^\circ\text{C}$ $T_C = 100^\circ\text{C}$	W
T_J, T_{STG}			$^\circ\text{C}$

Symbol	Unit
R	
R	

Electrical Characteristics ($T_J = 25^\circ\text{C}$ unless otherwise specified)

Symbol	Conditions	Min.	Typ.	Max.	Unit
Off Characteristics					
$V_{(BR)DSS}$		30	-	-	V
I_{DSS}		-	-	1.0	μA
I_{GSS}		-	-	± 100	nA

$V_{GS(th)}$

Typical Performance Characteristics

Figure 1: Power De-rating

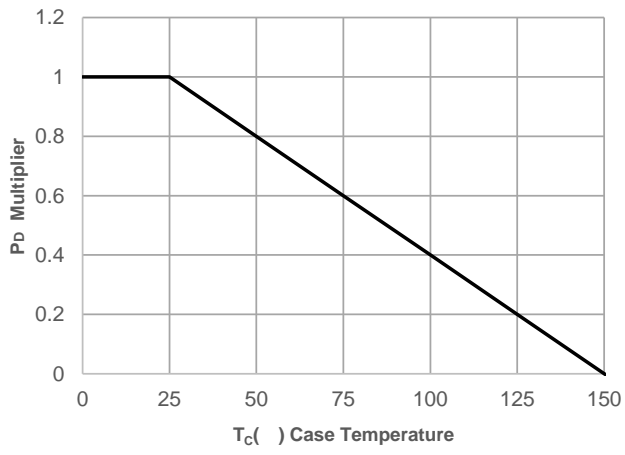
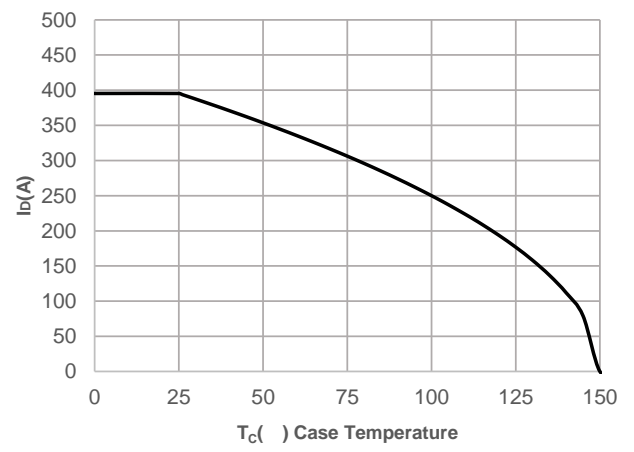
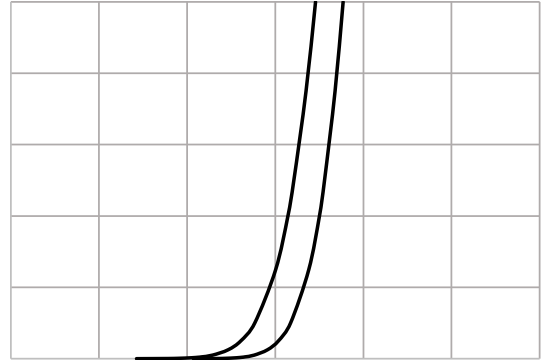
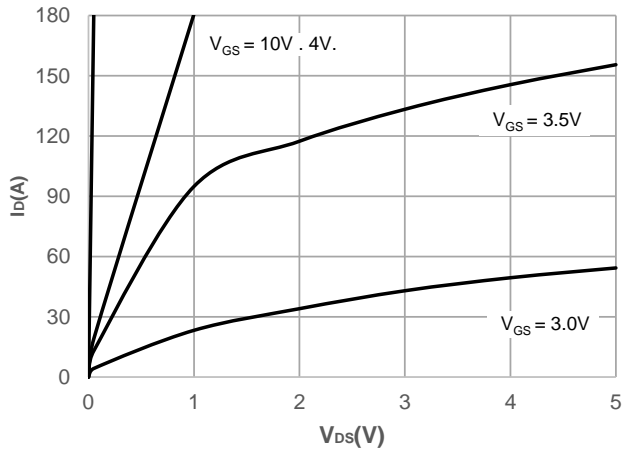


Figure 2: Current De-



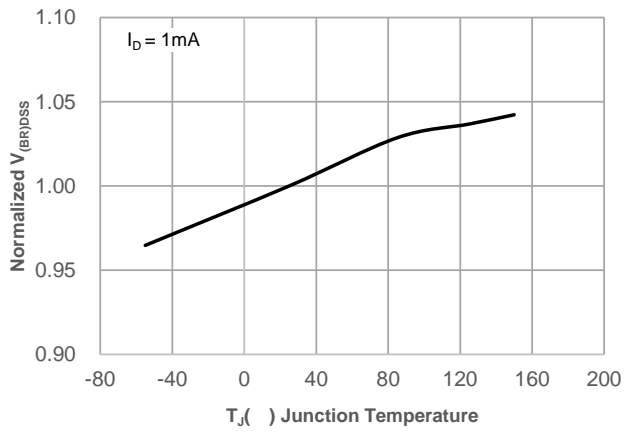
Typical Performance Characteristics

Figure 5: Output Characteristics



Typical Performance Characteristics

Figure 11: Normalized Breakdown voltage vs. Junction Temperature



Test Circuit



Figure 1: Gate Charge Test Circuit & Waveform

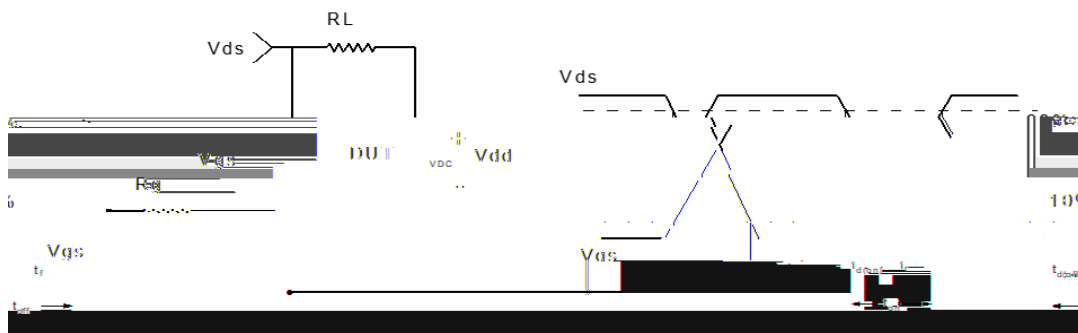


Figure 2: Resistive Switching Test Circuit & Waveform

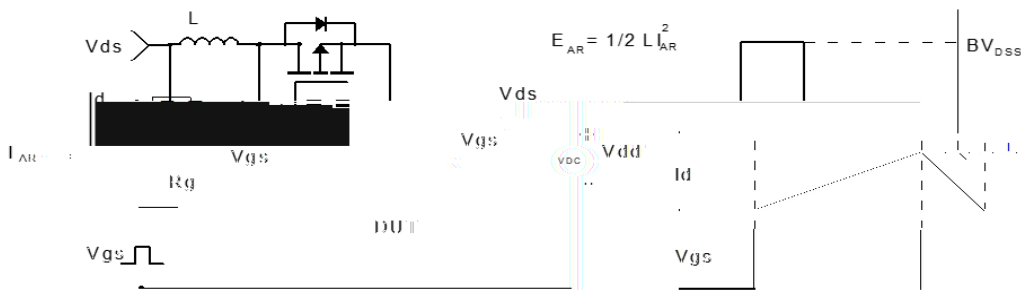


Figure 3: Unclamped Inductive Switching Test Circuit & Waveform



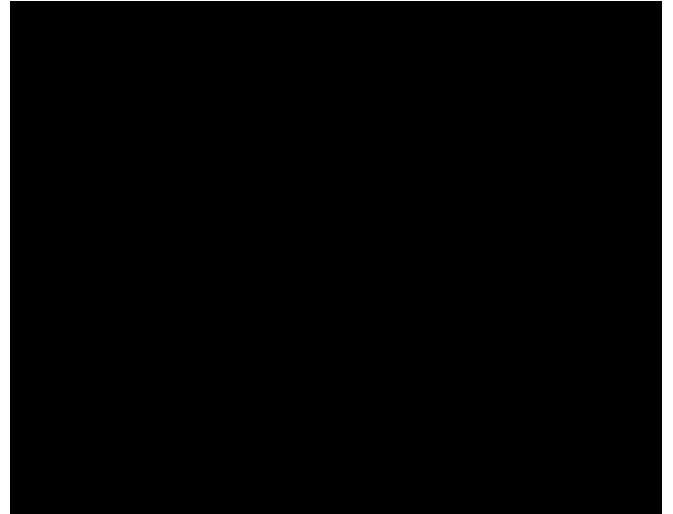
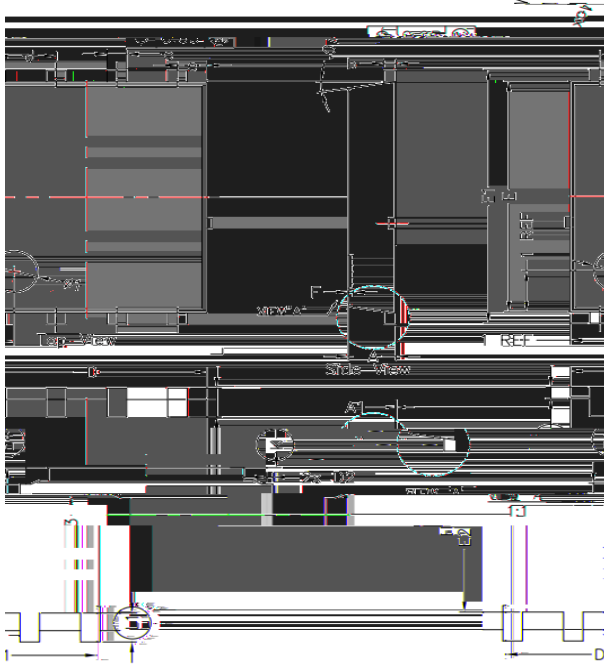
Figure 4: Diode Recovery Test Circuit & Waveform





Package Mechanical Data(PDFN 5X6-8L)

Package Outline



Information furnished in this document is believed to be accurate and reliable. However, Jiangsu JieJie Microelectronics Co.,Ltd assumes no responsibility for the consequences of use without consideration for such information nor use beyond it. Information mentioned in this document is subject to change without notice, apart from that when an agreement is signed, Jiangsu JieJie complies with the agreement. Products and information provided in this document have no infringement of patents. Jiangsu JieJie assumes no responsibility for any infringement of other rights of third parties which may result from the use of such products and information.

 is a registered trademark of Jiangsu JieJie Microelectronics Co.,Ltd.

